



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



## Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



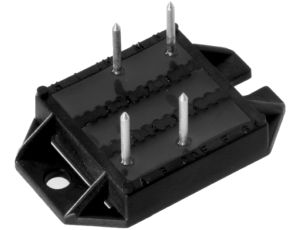
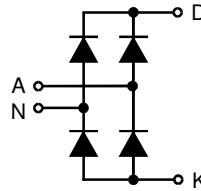
# ECO-PAC™

## Single Phase Rectifier Bridge

### with Fast Recovery Epitaxial Diodes (FRED)

$I_{dAV} = 19 \text{ A}$   
 $V_{RRM} = 1200 \text{ V}$   
 $t_{rr} = 40 \text{ ns}$

$V_{RSM}$ V	$V_{RRM}$ V	Typ
1200	1200	VBE 17-12NO7



Symbol	Conditions	Maximum Ratings	
$I_{dAV}$ ①	$T_C = 85^\circ\text{C}$ , module	19	A
$I_{dAVM}$		90	A
$I_{FSM}$	$T_{VJ} = 45^\circ\text{C}$ $V_R = 0$	$t = 10 \text{ ms}$ (50 Hz), sine	40 A
		$t = 8.3 \text{ ms}$ (60 Hz), sine	45 A
	$T_{VJ} = T_{VJM}$ $V_R = 0$	$t = 10 \text{ ms}$ (50 Hz), sine	35 A
		$t = 8.3 \text{ ms}$ (60 Hz), sine	40 A
$I^2t$	$T_{VJ} = 45^\circ\text{C}$ $V_R = 0$	$t = 10 \text{ ms}$ (50 Hz), sine	10 A <sup>2</sup> s
		$t = 8.3 \text{ ms}$ (60 Hz), sine	10 A <sup>2</sup> s
	$T_{VJ} = T_{VJM}$ $V_R = 0$	$t = 10 \text{ ms}$ (50 Hz), sine	5 A <sup>2</sup> s
		$t = 8.3 \text{ ms}$ (60 Hz), sine	5 A <sup>2</sup> s
$T_{VJ}$		-40...+150	°C
$T_{VJM}$		150	°C
$T_{stg}$		-40...+125	°C
$V_{ISOL}$	50/60 Hz, RMS $t = 1 \text{ min}$ $I_{ISOL} \leq 1 \text{ mA}$ $t = 1 \text{ s}$	3000	V~
		3600	V~
$M_d$ Weight	Mounting torque (M4) typ.	1.5-2/14-18	Nm/lb.in.
		19	g

#### Features

- Package with DCB ceramic base plate in low profile
- Isolation voltage 3000 V~
- Planar passivated chips
- Low forward voltage drop
- Leads suitable for PC board soldering

#### Applications

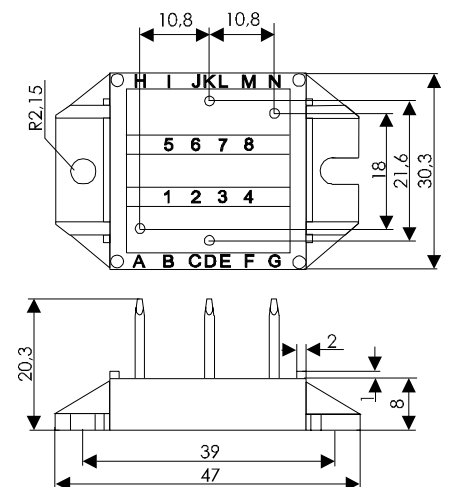
- Supplies for DC power equipment
- Input and output rectifiers for high frequency
- Battery DC power supplies
- Field supply for DC motors

#### Advantages

- Space and weight savings
- Improved temperature and power cycling capability
- Small and light weight
- Low noise switching

Symbol	Conditions	Characteristic Values	
		typ.	max.
$I_R$	$V_R = V_{RRM}$ $V_R = V_{RRM}$	$T_{VJ} = 25^\circ\text{C}$	0.06 mA
		$T_{VJ} = T_{VJM}$	0.25 mA
$V_F$	$I_F = 10 \text{ A}$ $T_{VJ} = 25^\circ\text{C}$		2.92 V
$V_{T0}$	for power-loss calculations only		1.32 V
$r_T$			30 mΩ
$R_{thJC}$ $R_{thCH}$	per diode; DC current per diode, DC current, typ.		2.5 K/W
			0.3 K/W
$I_{RM}$	$I_F = 12 \text{ A}$ , $-di/dt = 100 \text{ A}/\mu\text{s}$ $V_R = 100 \text{ V}$ , $L = 0.05 \text{ mH}$ , $T_{VJ} = 100^\circ\text{C}$	4	8.5 A
		$I_F = 1 \text{ A}$ ; $-di/dt = 50 \text{ A}/\mu\text{s}$ ; $V_R = 30 \text{ V}$ , $T_{VJ} = 25^\circ\text{C}$	40
$a$	Max. allowable acceleration	50	m/s <sup>2</sup>
$d_s$	creeping distance on surface	11.2	mm
$d_A$	creepage distance in air	9.7	mm

#### Dimensions in mm (1 mm = 0.0394")



Data according to IEC 60747 refer to a single diode unless otherwise stated  
 ① for resistive load at bridge output.

IXYS reserves the right to change limits, test conditions and dimensions.

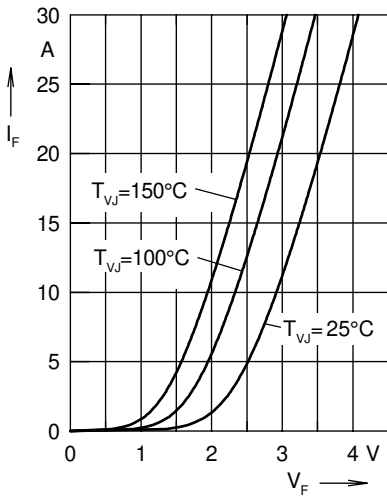


Fig. 1 Forward current  $I_F$  versus  $V_F$

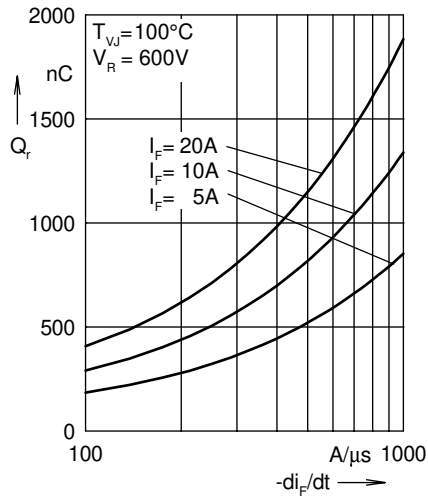


Fig. 2 Reverse recovery charge  $Q_r$  versus  $-di_F/dt$

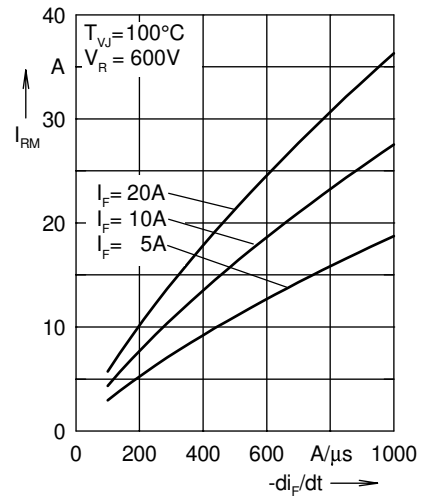


Fig. 3 Peak reverse current  $I_{RM}$  versus  $-di_F/dt$

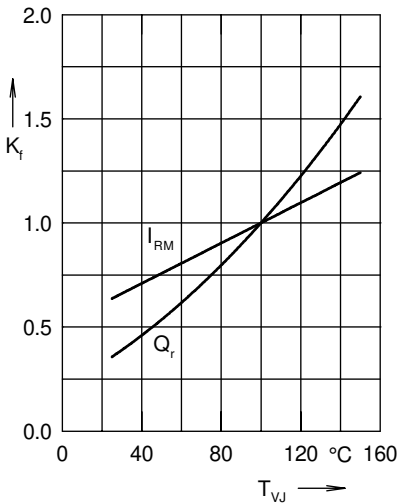


Fig. 4 Dynamic parameters  $Q_r$ ,  $I_{RM}$  versus  $T_{VJ}$

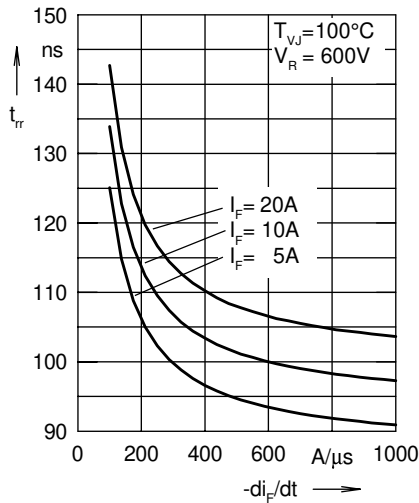


Fig. 5 Recovery time  $t_{rr}$  versus  $-di_F/dt$

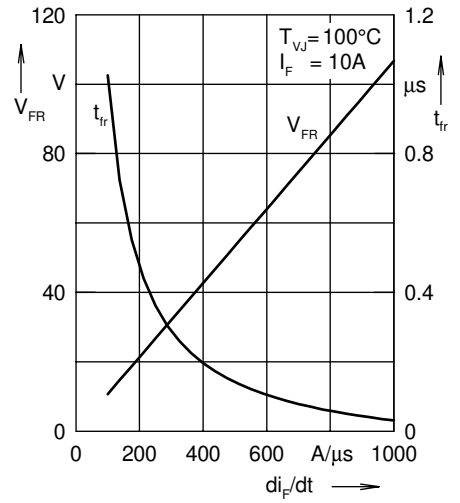


Fig. 6 Peak forward voltage  $V_{FR}$  and  $t_{fr}$  versus  $di_F/dt$

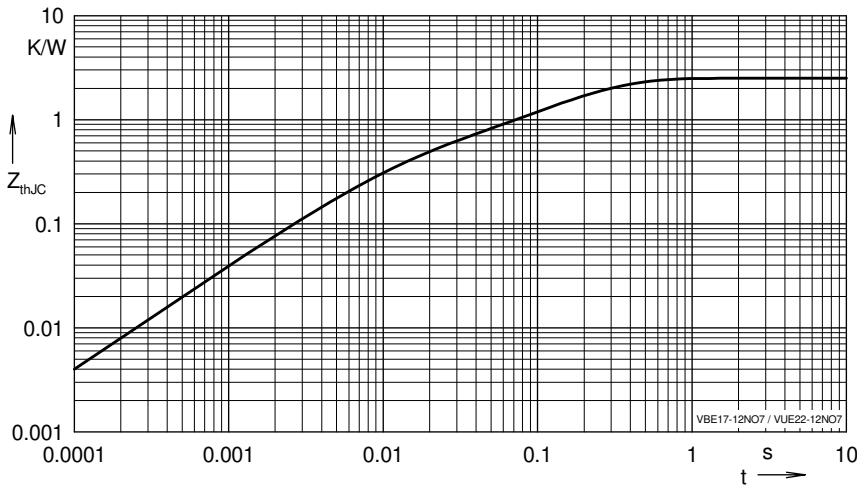


Fig. 7 Transient thermal resistance junction to case

Constants for  $Z_{thJC}$  calculation:

i	$R_{thi}$ (K/W)	$t_i$ (s)
1	0.8776	0.0052
2	0.3378	0.0003
3	0.0678	0.0004
4	1.2168	0.0092

NOTE: Fig. 2 to Fig. 6 shows typical values